

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Patent No. 7,141,472 B2
Patent Issue Date November 28, 2006
Application Serial No. 10/611,602
Filing Date June 30, 2003
Assignee Micron Technology, Inc.
Inventorship Hermes
Attorney's Docket No. MI22-2341
Title: Semiconductor Processing Methods of Forming Dynamic Random Access Memory (DRAM) Circuitry

**REQUEST FOR CERTIFICATE OF CORRECTION OF PATENT
FOR PTO MISTAKE (37 C.F.R. 1.322(a))**

To: Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

ATTN: Decision and Certificate of Correction
Branch of the Patent Issue Division

From: Jennifer J. Taylor, Ph.D. (Tel. 509-624-4276; Fax 509-838-3424)
Wells St. John P.S.
601 W. First Avenue, Suite 1300
Spokane, WA 99201-3828

Sir:

It is hereby requested that a Certificate of Correction be issued with respect to Patent No. 7,141,472 B2, granted November 28, 2006, in accordance with the Certificate of Correction form attached hereto.

The errors listed on the Certificate of Correction form were apparently incurred through the fault of the PTO as will be disclosed by the records of files in the Office.

Since this Certificate of Correction is being requested due to PTO errors, it is believed that no fee is due. However, in the event that a fee is required for issuance of this Certificate of Correction, please charge the fee specified under

37 C.F.R. § 1.20(a) to Deposit Account No. 23-0925. Please credit Deposit Account No. 23-0925 with any overpayment of the above fee.

Attached hereto is Form PTO-1050 which is suitable for printing.

Respectfully submitted,

Dated: July 3 2007

By:

Jennifer J. Taylor
Jennifer J. Taylor, Ph.D.
Reg. No. 48,711

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 7,141,472 B2

DATED : November 28, 2006

INVENTOR(S) : Hermes

It is certified that errors appear in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 2, Line 34 – Replace “subsequent; to” with --subsequent to--.

Column 4, Line 31 – Replace “common, etch” with --common etch--.

Column 4, Line 37 – Replace “Accordingly;” with --Accordingly,--.

Column 5, Line 31 – Replace “under-and” with --under and--.

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